

INTRODUCE:

HVGT high voltage silicon rectifier diodes is made of high quality silicon wafer chip and high reliability epoxy resin sealing structure, and through professional testing equipment inspection qualified after to customers.

FEATURES:

1. Fast recovery.
2. High reliability design.
3. Low current, high voltage.
4. Conform to RoHS and SGS.
5. Epoxy resin molded in vacuumHave anticorrosion in the surface.

APPLICATIONS:

1. Air purification, negative ions.
2. Electrostatic voltage doubling circuit.
3. Copier and X-ray.
4. Other high voltage rectifier circuits.

MECHANICAL DATA:

1. Case: epoxy resin molding.
2. Terminal: welding axis.
3. Net weight: 0.28 grams (approx).

SHAPE DISPLAY:

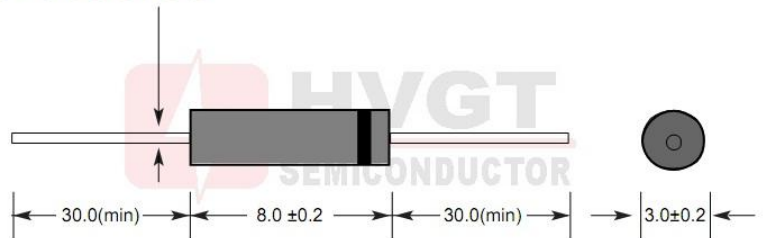


SIZE: (Unit:mm)

HVGT NAME: DO-308

DO-308 Series

Lead Diameter 0.6±0.03



Unit:mm

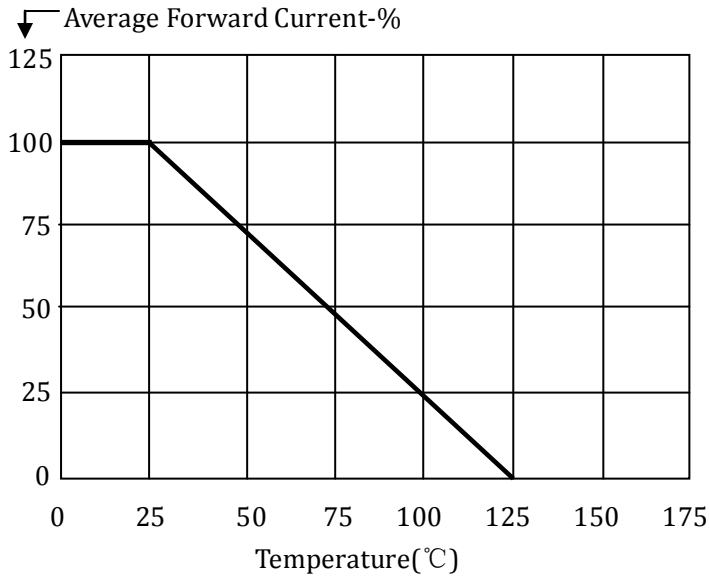
MAXIMUM RATINGS AND CHARACTERISTICS: (Absolute Maximum Ratings)

Items	Symbols	Condition	Data Value	Units
Repetitive Peak Reverse Voltage	V_{RRM}	$T_A=25^{\circ}C$	12	kV
Non-Repetitive Peak Reverse Voltage	V_{RSM}	$T_A=25^{\circ}C$	--	kV
Average Forward Current Maximum	I_{FAVM}	$T_A=25^{\circ}C$	5.0	mA
		$T_{OIL}=55^{\circ}C$	--	mA
Non-Repetitive Forward Surge Current	I_{FSM}	$T_A=25^{\circ}C$; 60Hz Half-Sine Wave; 8.3mS	0.5	A
Junction Temperature	T_J		125	$^{\circ}C$
Allowable Operation Case Temperature	T_c		-40~+125	$^{\circ}C$
Storage Temperature	T_{STG}		-40~+125	$^{\circ}C$

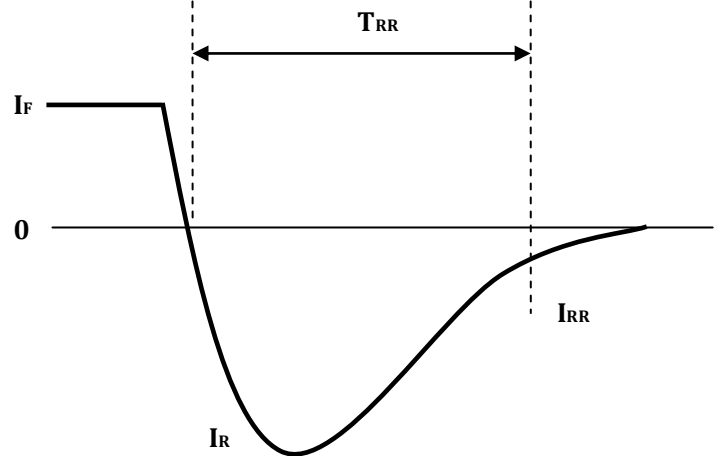
ELECTRICAL CHARACTERISTICS: $T_A=25^{\circ}C$ (Unless Otherwise Specified)

Items	Symbols	Condition	Data value	Units
Maximum Forward Voltage Drop	V_{FM}	at $25^{\circ}C$; at I_{FAVM}	35	V
Maximum Reverse Current	I_{R1}	at $25^{\circ}C$; at V_{RRM}	2.0	μA
	I_{R2}	at $100^{\circ}C$; at V_{RRM}	5.0	μA
Maximum Reverse Recovery Time	T_{RR}	at $25^{\circ}C$; $I_f=0.5I_R$; $I_R=I_{FAVM}$; $I_{RR}=0.25I_R$	80	nS
Junction Capacitance	C_J	at $25^{\circ}C$; $V_R=0V$; $f=1MHz$	1.0	pF

Forward Current Derating Curve

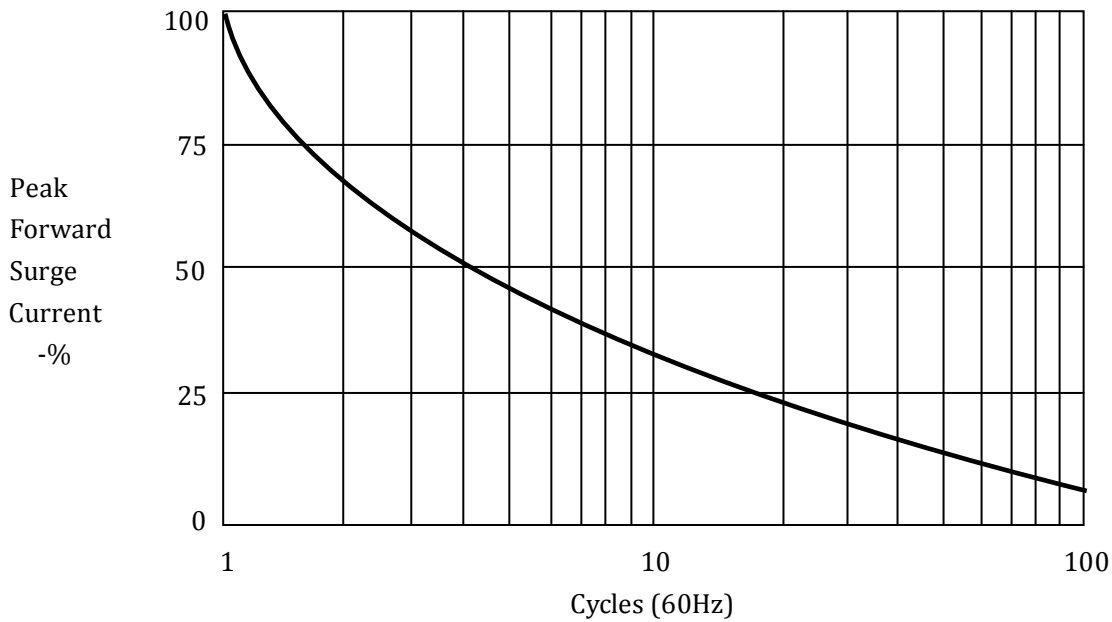



Reverse Recovery Measurement Waveform



Typical data capture points: $I_F = 0.5I_R$, $I_R, I_{RR} = 0.25I_R$
 I_R is typically the rated average forward current maximum (I_{FAVM}) of the D.U.T

Non-Repetitive Surge Current



Marking	Type	Code	Cathode Mark
	ESJA59-12A		
Packing in bulk	500Pcs/bag	4000Pcs/box	24000Pcs/Out box
Size:	18.0x11.8mm	230x150x72mm	321x248x263mm
Gross weight:	145g	1280g	8030g

Note: The suffix "TR" of this model indicates the tape packaging.

Not "TR" means bulk packaging.